

## **PBSS4250X**

50 V, 2 A NPN low VCEsat transistor

11 September 2023

**Product data sheet** 

## 1. General description

NPN low  $V_{\text{CEsat}}$  transistor in a SOT89 (SC-62) flat lead Surface-Mounted Device (SMD) plastic package.

PNP complement: PBSS5250X

## 2. Features and benefits

- Low collector-emitter saturation voltage V<sub>CEsat</sub>
- + High collector current capability:  $I_{C}$  and  $I_{CM}$
- Higher efficiency leading to less heat generation
- Reduced printed-circuit board requirements
- AEC-Q101 qualified

#### 3. Applications

- Power management
  - DC/DC converters
  - Supply line switching
  - Battery charger
  - LCD backlighting
  - Peripheral drivers
  - Driver in low supply voltage applications (e.g. lamps and LEDs)
  - Inductive load driver (e.g. relays, buzzers and motors)

#### 4. Quick reference data

Table 1. Quick reference data							
Symbol	Parameter	Conditions		Min	Тур	Мах	Unit
V <sub>CEO</sub>	collector-emitter voltage	open base		-	-	50	V
I <sub>C</sub>	collector current			-	-	2	A
h <sub>FE</sub>	DC current gain	V <sub>CE</sub> = 2 V; I <sub>C</sub> = 0.1 A; T <sub>amb</sub> = 25 °C		300	-	-	

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## 5. Pinning information

Pin	Symbol	Description	Simplified outline	Graphic symbol
1	E	emitter		С
2	С	collector		
3	В	base		B
			SOT89	sym123

## 6. Ordering information

Table 3. Ordering information						
Type number Package						
	Name	Description	Version			
PBSS4250X		plastic, surface-mounted package; 3 leads; 1.5 mm pitch; 4.5 mm x 2.5 mm x 1.5 mm body	<u>SOT89</u>			

## 7. Marking

Table 4. Marking codes	
Type number	Marking code[1]
PBSS4250X	%1M

[1] % = placeholder for manufacturing site code

## 8. Limiting values

#### Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions		Min	Max	Unit
V <sub>CBO</sub>	collector-base voltage	open emitter		-	50	V
V <sub>CEO</sub>	collector-emitter voltage	open base		-	50	V
V <sub>EBO</sub>	emitter-base voltage	open collector		-	5	V
I <sub>C</sub>	collector current			-	2	А
I <sub>CM</sub>	peak collector current	limited by $T_{j(max)}$ ; single pulse; $t_p \le 1 \text{ ms}$		-	5	А
IB	base current			-	0.5	А
P <sub>tot</sub>	total power dissipation	T <sub>amb</sub> ≤ 25 °C	[1]	-	550	mW
			[2]	-	1	W
Tj	junction temperature			-	150	°C
T <sub>amb</sub>	ambient temperature			-65	150	°C
T <sub>stg</sub>	storage temperature			-65	150	°C

[1] Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint.

[2] Device mounted on an FR4 PCB, single-sided copper, tin-plated, mounting pad for collector 1 cm<sup>2</sup>.

## 9. Thermal characteristics

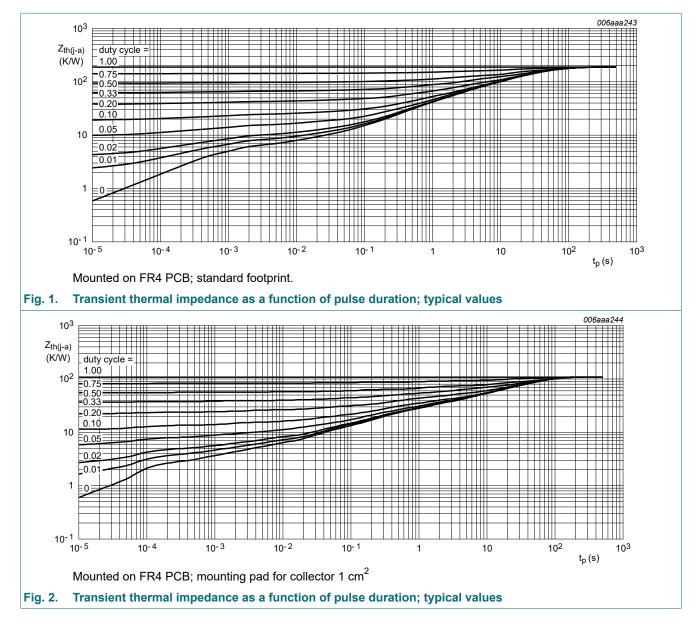
Symbol	Parameter	Conditions		Min	Тур	Max	Unit
R <sub>th(j-a)</sub>	thermal resistance from junction to ambient	rmal resistance from in free air ction to ambient	[1]	-	-	225	K/W
			[2]	-	-	125	K/W
			[3]	-	-	90	K/W
			[4]	-	-	80	K/W
R <sub>th(j-sp)</sub>	thermal resistance from junction to solder point			-	-	16	K/W

Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint. [1]

Device mounted on an FR4 PCB, single-sided copper, tin-plated, mounting pad for collector 1 cm<sup>2</sup> [2]

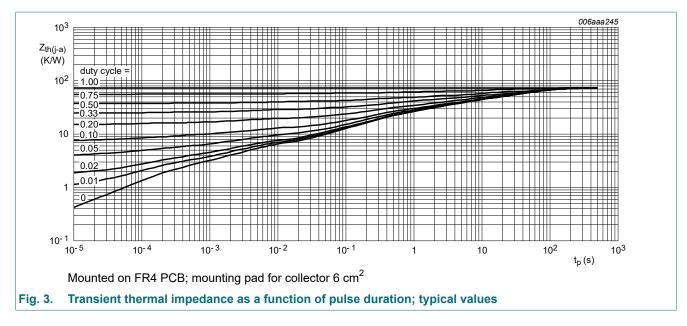
Device mounted on an FR4 PCB, single-sided copper, tin-plated, mounting pad for collector 6 cm<sup>2</sup>. Device mounted on a ceramic PCB, 7 cm<sup>2</sup>, single-sided copper, tin-plated. [3]

[4]



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#### **10. Characteristics**

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
I <sub>CBO</sub>	collector-base cut-off	V <sub>CB</sub> = 50 V; I <sub>E</sub> = 0 A; T <sub>amb</sub> = 25 °C	-	-	100	nA
	current	V <sub>CB</sub> = 50 V; I <sub>E</sub> = 0 A; T <sub>j</sub> = 150 °C	-	-	50	μA
I <sub>EBO</sub>	emitter-base cut-off current	V <sub>EB</sub> = 5 V; I <sub>C</sub> = 0 A; T <sub>amb</sub> = 25 °C	-	-	100	nA
I <sub>CES</sub>	collector-emitter cut-off current	$V_{CE} = 50 \text{ V}; \text{ V}_{BE} = 0 \text{ V}; \text{ T}_{amb} = 25 \text{ °C}$	-	-	100	nA
h <sub>FE</sub>	DC current gain	V <sub>CE</sub> = 2 V; I <sub>C</sub> = 0.1 A; T <sub>amb</sub> = 25 °C	300	-	-	
		V <sub>CE</sub> = 2 V; I <sub>C</sub> = 0.5 A; T <sub>amb</sub> = 25 °C	300	-	-	
		$V_{CE}$ = 2 V; I <sub>C</sub> = 1 A; pulsed; t <sub>p</sub> ≤ 300 µs; $\delta$ ≤ 0.02; T <sub>amb</sub> = 25 °C	300	-	-	
		$V_{CE}$ = 2 V; I <sub>C</sub> = 2 A; pulsed; t <sub>p</sub> ≤ 300 µs; $\delta$ ≤ 0.02; T <sub>amb</sub> = 25 °C	150	-	-	
V <sub>CEsat</sub>	collector-emitter saturation voltage	$I_{C}$ = 0.5 A; $I_{B}$ = 50 mA; $T_{amb}$ = 25 °C	-	-	90	mV
		I <sub>C</sub> = 1 A; I <sub>B</sub> = 50 mA; T <sub>amb</sub> = 25 °C	-	-	250	mV
		$I_{C}$ = 2 A; $I_{B}$ = 100 mA; $T_{amb}$ = 25 °C	-	-	380	mV
		$I_C$ = 2 A; $I_B$ = 200 mA; pulsed; $t_p \le$	-	-	320	mV
R <sub>CEsat</sub>	collector-emitter saturation resistance	300 μs; δ ≤ 0.02; T <sub>amb</sub> = 25 °C	-	-	160	mΩ
V <sub>BEsat</sub>	base-emitter saturation voltage	I <sub>C</sub> = 2 A; I <sub>B</sub> = 100 mA; T <sub>amb</sub> = 25 °C	-	-	1.1	V
V <sub>BEon</sub>	base-emitter turn-on voltage	V <sub>CE</sub> = 2 V; I <sub>C</sub> = 1 A; T <sub>amb</sub> = 25 °C	-	-	1.1	V
f <sub>T</sub>	transition frequency	V <sub>CE</sub> = 5 V; I <sub>C</sub> = 100 mA; f = 100 MHz; T <sub>amb</sub> = 25 °C	100	-	-	MHz
C <sub>c</sub>	collector capacitance	V <sub>CB</sub> = 10 V; I <sub>E</sub> = 0 A; i <sub>e</sub> = 0 A; f = 1 MHz; T <sub>amb</sub> = 25 °C	-	-	25	pF

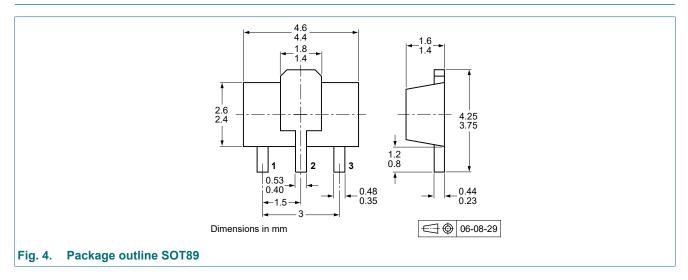
#### Table 7 Characteristics

#### **11. Test information**

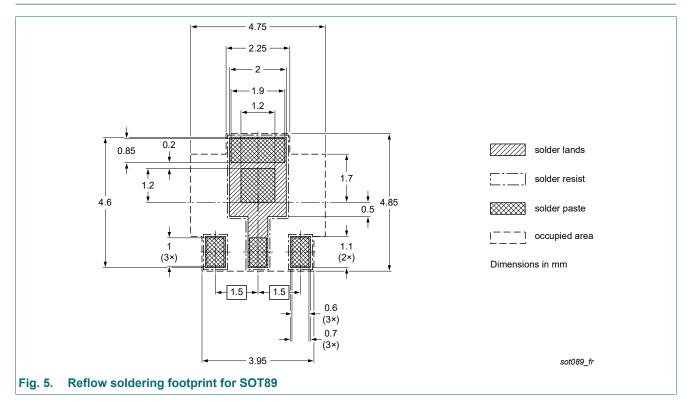
#### **Quality information**

This product has been qualified in accordance with the Automotive Electronics Council (AEC) standard *Q101* - *Stress test qualification for discrete semiconductors*, and is suitable for use in automotive applications.

#### 12. Package outline

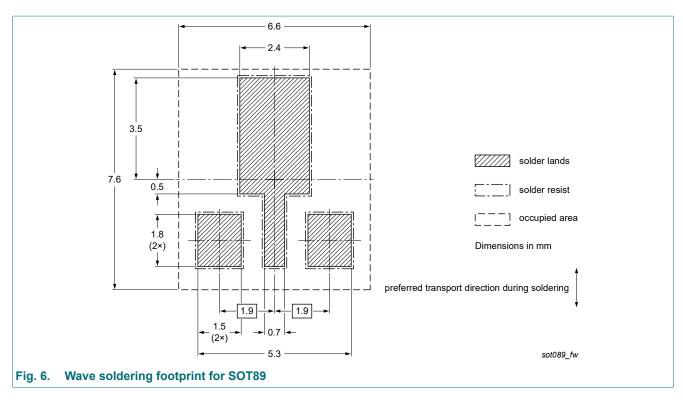


#### 13. Soldering



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## 14. Revision history

Table 8. Revision histo	ory			
Data sheet ID	Release date	Data sheet status	Change notice	Supersedes
PBSS5250X v.4	20230911	Product data sheet	-	PBSS5250X v.2
Modifications:	Characterist	ics, typo corrected at V <sub>BEor</sub>	: value changed	from min to max
PBSS5250X v.3	20230424	Product data sheet	-	PBSS5250X v.2
PBSS5250X v.2	20041108	Product data sheet	-	PBSS5250X v.1
PBSS5250X v.1	20030617	Product specification	-	-

## 15. Legal information

#### **Data sheet status**

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

 Please consult the most recently issued document before initiating or completing a design.

- [2] The term 'short data sheet' is explained in section "Definitions".
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